

NPN POWER TRANSISTOR

These devices are high voltage, high speed transistors for horizontal deflection output stages of TV"s and CTV"s circuits.

FEATURES:

* Collector-Emitter Sustaining Voltage -

V_{CEV} = 330 V (Min.) - BU407 = 400 V (Min.) - BU406

* Low Saturation Voltage

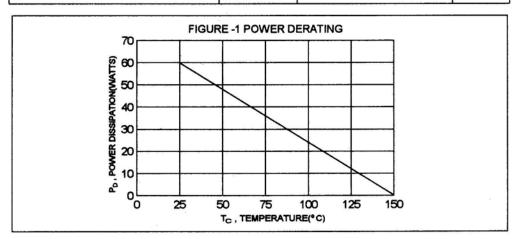
V_{CE(sat)}=1.0V(Max) @I_C=5.0A * Fast Switching Speed: tf=0.75 us (Max)

MAXIMUM RATINGS

| Characteristic | Symbol | BU406 | BU407 | Unit |
|--|----------------------------------|--------------|-------|------|
| Collector-Emitter Voltage | V _{CEO} | 200 | 150 | v |
| Collector-Emitter Voltage | V _{CEV} | 400 | 330 | V |
| Collector-Bse Voltage | V _{CBO} | 400 | 330 | V |
| Emitter-Base Voltage | V _{EBO} | 6.0 | | V |
| Collector Current - Continuous - Peak | l _c | 7.0 10 | | Α |
| Base Current - Continuous | I _B | 4.0 | | Α |
| Total Power Dissipation @T _C =25°C Derate above 25°C | P _D | 60 0.48 | | w/°c |
| Operating and Storage Junction Temperature Range | T _J ,T _{STG} | - 65 to +150 | | °C |

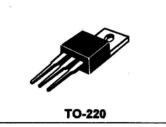
THERMAL CHARACTERISTICS

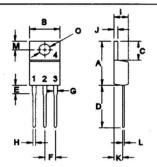
| Characteristic | Symbol | Max | Unit |
|-------------------------------------|--------|------|------|
| Thermal Resistance Junction to Case | R⊕jc | 2.08 | °C/W |



NPN **BU406 BU407**

7 AMPERE **POWER TRANSISTORS** 150-200 VOLTS 60 WATTS





PIN 1.BASE 2.COLLECTOR 3.EMITTER 4.COLLECTOR(CASE)

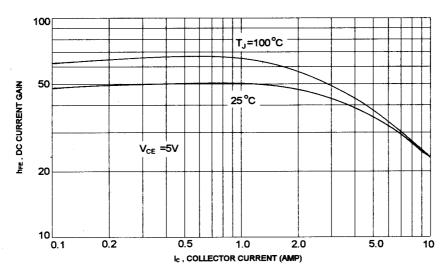
| DIM | MILLIMETERS | | | |
|-----|-------------|-------|--|--|
| | MIN | MAX | | |
| Α | 14.68 | 16.00 | | |
| В | 9.78 | 10.42 | | |
| С | 5.02 | 6.60 | | |
| D | 13.00 | 14.62 | | |
| E | 3.10 | 4.19 | | |
| F | 2.41 | 2.67 | | |
| G | 1.10 | 1.67 | | |
| Н | 0.69 | 1.01 | | |
| I | 3.21 | 4.98 | | |
| J | 1.14 | 1.40 | | |
| K | 2.20 | 3.30 | | |
| L | 0.28 | 0.61 | | |
| М | 2.48 | 3.00 | | |
| 0 | 3.50 | 4.00 | | |

ELECTRICAL CHARACTERISTICS (T_c = 25°C unless otherwise noted)

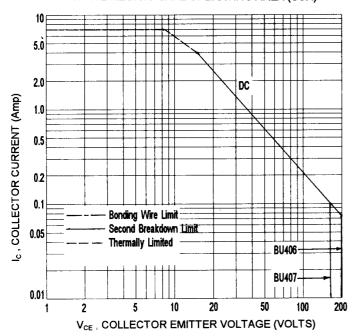
| Characteristic | Symbol | Min | Max | Unit |
|--|-----------------------|------------|------------|------|
| OFF CHARACTERISTICS | | | | |
| Collector - Emitter Sustaining Voltage (1) (I _C = 100 mA, I _B = 0) BU406 BU407 | V _{CEO(SUS)} | 200 150 | | v |
| Collector Cutoff Current (V _{CE} = 400 V, V _{BE} = 0) BU406 (V _{CE} = 330 V, V _{BE} = 0) BU407 | I _{CES} | | 5.0 5.0 | mA |
| Emitter Cutoff Current (V _{EB} = 6.0 V,I _C = 0) | EBO | | 1.0 | mA |
| ON CHARACTERISTICS (1) | | | | |
| DC Current Gain (I _C =2.0 A , V _{CE} = 5.0 V) | hFE | 30(typ) | | |
| Collector - Emitter Saturation Voltage (I _C =5.0 A, I _B = 0.5 A) | V _{CE(sat)} | | 1.0 | V |
| Base - Emitter Saturation Voltage (I _C =5.0 A, I _B = 0.5 A) | V _{BE(sat)} | | 1.2 | V |
| DYNAMIC CHARACTERISTICS | | | | |
| Current Gain - Bandwidth Product (I _C = 0.5 A, V _{CE} = 10 V, f = 1.0 MHz) | f _T | 10 | | MHz |
| Output Capacitance (V _{CE} =10V, I _E =0, f=1.0 MHz) | C _{ob} | 80(typ) | | pF |
| SWITCHING CHARACTERISTICS | | | | |
| Fall Time (V _{CC} =40 V, I _C =5.0 A, I _{B1} =-I _{B2} = 0.6A, L=150 uH) | t, | | 0.75 | us |

⁽¹⁾ Pulse Test: Pulse width \leq 300 us , Duty Cycle \leq 2.0%





ACTIVE-REGION SAFE OPERATING AREA (SOA)



There are two limitation on the power handling ability of a transistor:average junction temperature and second breakdown safe operating area curves indicate $l_{\text{C}}\text{-}V_{\text{CE}}$ limits of the transistor that must be observed for reliable operation i.e., the transistor must not be subjected to greater dissipation than curves indicate.

The data of SOA curve is base on $T_{J(PK)}$ =150 °C; T_C is variable depending on conditions, second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(PK)}$ ≤150°C,At high case temperatures, thermal limitation will reduce the power that can be handled to values less than the limitations imposed by second breakdown.



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